



UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE
United States Patent and Trademark Office
Address: COMMISSIONER FOR PATENTS
P.O. Box 1450
Alexandria, Virginia 22313-1450
www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/702,615	11/07/2003	In Duk Song	8733.930.00-US	8495
30827	7590	09/07/2005	EXAMINER	
MCKENNA LONG & ALDRIDGE LLP 1900 K STREET, NW WASHINGTON, DC 20006			KIM, RICHARD H	
		ART UNIT	PAPER NUMBER	
		2871		

DATE MAILED: 09/07/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No.	Applicant(s)
	10/702,615	SONG ET AL. 
	Examiner	Art Unit
	Richard H. Kim	2871

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) Responsive to communication(s) filed on ____.
- 2a) This action is FINAL. 2b) This action is non-final.
- 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) Claim(s) 1-12 is/are pending in the application.
 - 4a) Of the above claim(s) 5-8 is/are withdrawn from consideration.
- 5) Claim(s) ____ is/are allowed.
- 6) Claim(s) 1-4 and 9-12 is/are rejected.
- 7) Claim(s) ____ is/are objected to.
- 8) Claim(s) ____ are subject to restriction and/or election requirement.

Application Papers

- 9) The specification is objected to by the Examiner.
- 10) The drawing(s) filed on 07 November 2003 is/are: a) accepted or b) objected to by the Examiner.

Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).

Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
 - a) All b) Some * c) None of:
 1. Certified copies of the priority documents have been received.
 2. Certified copies of the priority documents have been received in Application No. ____.
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892)	4) <input type="checkbox"/> Interview Summary (PTO-413)
2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail Date. ____.
3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date ____.	5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152)
	6) <input type="checkbox"/> Other: ____.

DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

2. Claims 1, 2, 4, 9, 10 and 12 are rejected under 35 U.S.C. 102(b) as being anticipated by Ono et al. (US 6,726,802 B2).

As to claim 1, Ono et al. discloses a plurality of gate lines aligned on the substrate, a plurality of data lines crossing the gate lines to form a plurality of pixel regions (Fig. 19, ref. GL, DL); a thin film transistor located at the intersection of a gate line and a data line (TFT); a pixel electrode located in each pixel region (PX), wherein the array substrate further comprises a storage capacitor comprising a lower storage electrode across the data line and in parallel with the gate line on the same layer as the gate line (CTg1); and a semiconductor layer interposed between the lower storage electrode and the pixel electrode (AS). As to the product-by-process limitation “by a diffraction pattern”, it has been recognized that “Even though product-by-process claims a limited by and defined by the process, determination of the patentability is based on the product by itself. The product does not depend on its method of production. If the product in the product-by-process claim is the same as or obvious from a product of the prior art, the claim is unpatentable even though the prior art product was made by a different process”. *In re Thorpe*, 227 USPQ 964, 966 (Fed. Cir. 1985). MPEP 2113.

As to claim 2, Ono et al. discloses that the pixel electrode is connected to the semiconductor layer by a through hole formed on an upper region of the semiconductor layer (Fig. 21, ref. AS, PX).

Referring to claim 4, Ono et al. discloses that only the semiconductor layer and a gate insulating layer are interposed between the lower storage electrode and the pixel electrode (GI, AS).

Referring to claim 9, Ono et al. discloses a gate line (GL), a gate electrode (GL), a lower storage capacitor (Cstg), and an upper storage electrode on the substrate (PX); an insulating layer (GI), a semiconductor layer exposed on the lower storage electrode (AS), an impure semiconductor layer as a source/drain electrode (AS), and a metal layer as a data line on the gate line, the gate electrode and the lower storage capacitor (DL); a protection layer on the data line, the source/drain electrode, and the exposed semiconductor layer PSV; the protection layer having a contact hole and a through hole above a port of the drain electrode and the exposed semiconductor layer (PSV); and a transparent electrode on the protection layer (ITO1), wheren the gate line and data line cross to forma pixel region (GL, DL); and wherein the transparent electrode is connected to the drain electrode through the contact hole (CN).

As to claim 10, Ono et al. discloses that the pixel electrode is connected to the semiconductor layer by a through hole formed on an upper region of the semiconductor layer (Fig. 21, ref. AS, PX).

Referring to claim 12, Ono et al. discloses that only the semiconductor layer and a gate insulating layer are interposed between the lower storage electrode and the pixel electrode (GI, AS).

Claim Rejections - 35 USC § 103

3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

4. Claims 3 and 11 is rejected under 35 U.S.C. 103(a) as being unpatentable over Ono et al.

Ono et al. discloses the device previously recited, and further discloses that the semiconductor layer is inside the pixel region (Fig. 21, ref. AS). However, the reference fails to disclose that the semiconductor layer is at least as wide as the lower storage electrode.

It would have been obvious to one having ordinary skill in the art at the time the invention was made for the semiconductor region to be at least as wide as the lower storage electrode since Ono et al. discloses that the semiconductor layer increases the charge holding capacitance value per area (col. 24, lines 24-25). Therefore, increasing the width, in order to increase the charge holding capacitance is a result effective variable and requires only routine skill in the art.

Conclusion

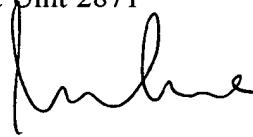
Any inquiry concerning this communication or earlier communications from the examiner should be directed to Richard H. Kim whose telephone number is (571)272-2294. The examiner can normally be reached on 9:00-6:30 M-F.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Robert H. Kim can be reached on (571)272-2293. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Richard H Kim
Examiner
Art Unit 2871

RHK



JUNG T. NGUYEN
PRIMARY EXAMINER